Datasheet



Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceed the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-35835
 - Class Q Military
 - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)

• Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

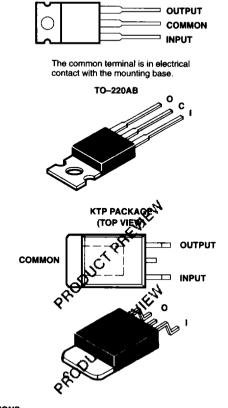
KC PACKAGE (TOP VIEW)

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- 3-Terminal Regulators
- Output Current Up to 500 mA
- No External Components
- Internal Thermal Overload Protection
- High Power Dissipation Capability
- Internal Short-Circuit Current Limiting
- Output Transistor Safe-Area Compensation
- Direct Replacements for Fairchild µA78M00 Series

description

This series of fixed-voltage monolithic integratedcircuit voltage regulators is designed for a wide range of applications. These applications include on-card regulation for elimination of noise and distribution problems associated with single-point regulation. Each of these regulators can deliver up to 500 mA of output current. The internal current limiting and thermal shutdown features of these regulators make them essentially immune to overload. In addition to use as fixed-voltage regulators, these devices can be used with external components to obtain adjustable output voltages and currents and also as the power pass element in precision regulators.



		AVAILABLE OPTIC	ONS	
	N-(nom)	PACKAGE	D DEVICES	CHIP
TA	V _O (nom) (V)	HEAT-SINK MOUNTED (KC)	HEAT-SINK MOUNTED	FORM (Y)
	5	μA78M05CKC	μA78M05CCT	μ Α78M05 Υ
	6	µA78M06CKC	HA78MACKT	μ Α78Μ0 6Υ
	8	µA78M08CKC	HAZENBOK	μ Α78Μ08 Υ
	9	µА78М09СКС	ZIMOOKTP	μ Α78Μ0 9Υ
0°C to 125°C	10	μA78M10CKC	UAZENCIOCKTP	μ Α78Μ10 Υ
	12	μA78M12CKC	MI12CKTP	μ Α78Μ12 Υ
	15	μA78M15CKC	A78M15CKTP	μ Α78Μ1 5Υ
	20	μA78M20CKC	µА78М20СКТР	μ Α78Μ2 0Υ
	24	μA78M24CKC	μA78M24CKTP	μ Α78Μ24 Υ

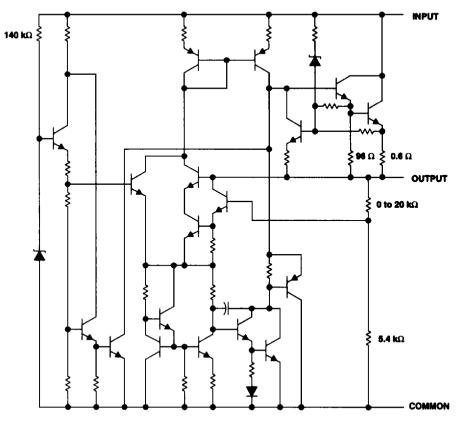
[†] The KTP package is only available in tape and reel.

UNLESS OTHERWISE NOTED this document contains PRODUCTION DATA information current as of publication date. Products conform to appendications per the strame of rease instruments standard: warranty. Production processing does not necessarily include testing of all parameters.



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schematic



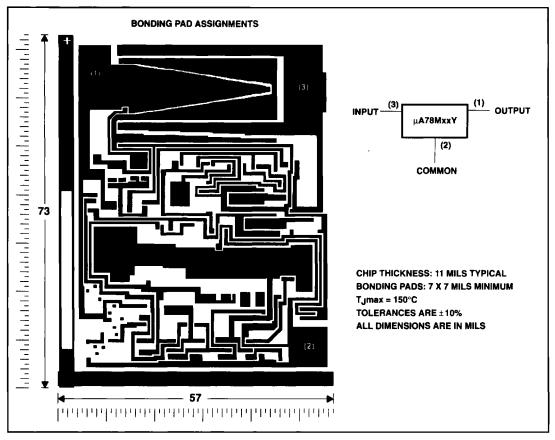
Resistor values shown are nominal.



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µA78MxxY chip Information

This chip, when properly assembled, displays characteristics similar to the μ A78MxxC. Thermal compression or ultrasonic bonding can be used on the doped aluminum bonding pads. The chip can be mounted with conductive epoxy or a gold-silicon preform.





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absolute maximum ratings over operating temperature range (unless otherwise noted)[†]

		μ Α78Μ ΧΧ	UNIT
	μΑ78M20, μΑ78M24	-40	v
Input voltage, V	All others	35	1 °
Continuous total power dissipation (see Note 1)		See Dissipation Rating Tables	1 and 2
Operating free-air (TA), case (TC), or virtual junction (TJ) temperature	erature range	0 to 150	°C
Storage temperature range, Tsto		-65 to 150	°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	3	260	°C.

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: To avoid exceeding the design maximum virtual junction temperature, these ratings should not be exceeded. Due to variations in individual device electrical characteristics and thermal resistance, the built-in thermal overload protection may be activated at power levels slightly above or below the rated dissipation.

DISSIPATION RATING TABLE 1 - FREE-AIR TEMPERATURE

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING
кс	2000 mW	16 mW/°C	1280 mW
KTD t			

† The KTP package is product preview only and derating information is not yet available.

DISSIPATION RATING TABLE 2 - CASE TEMPERATURE

PACKAGE	T _C ≤ 50°C POWER RATING	DERATING FACTOR ABOVE T _C = 50°C	T _C = 125°C POWER RATING
кс	20 W	200 mW/°C	5 W
KTP1			

[†] The KTP package is product preview only and derating information is not yet available.

recommended operating conditions

		MIN	MAX	UNIT
	μA78M05	7	25	
	μ Α78M06	8	25	1
	μ Α78M08	10.5	25	1
	μ Α78 Μ09	11.5	26	1
Input voltage, V	μ Α78Μ 10	12.5	28	v
	μ A78M 12	14.5	30	1
	μ A78M15	17.5	30	
	μA78M20	23	35	
	μA78M24	27	38	
Output current, IO			500	mA
Operating virtual junction temperature, Tj		0	125	ç



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			μ Α78M05C			
PARAMETER	TEST CO	NDITIONS	MIN	TYP	MAX	UNIT
Out			4.8	5	5.2	v
Output voltage [‡]	$V_{l} = 7 V \text{ to } 20 V,$	T _J = 0°C to 125°C	4.75		5.25	1 [×]
		V _I = 7 V to 25 V		3	100	
Input voltage regulation	IO = 200 mA	VI = 8 V to 20 V				mV
		VI = 8 V to 25 V		1	50	1
- Ripple rejection	Vi = 8 V to 18 V,	IO = 100 mA, TJ = 0°C to 125°C	62			dB
	f = 120 Hz	IO = 300 mA	62	80		1
	IO = 5 mA to 500 mA		20	100		
Output voltage regulation	IO = 5 mA to 200 mA			10	50	mV
Temperature coefficient of output voltage	IO = 5 mA	T _J = 0°C to 125°C		-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz			40	200	μV
Dropout voltage				2	2.5	V
Bias current				4.5	6	mA
Bias current change	I _O = 200 mA, T _J = 0°C to 125°C	$V_{I} = 8 V \text{ to } 25 V,$	-		0.8	mA
	IO = 5 mA to 350 mA	TJ = 0°C to 125°C			0.5	1
Short-circuit output current	VI = 35 V			300		mA
Peak output current				0.7		A

electrical characteristics at specified virtual junction temperature, $V_I = 10$ V, $I_O = 350$ mA, $T_J = 25^{\circ}$ C (unless otherwise noted)

¹ All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

[‡] This specification applies only for dc power dissipation permitted by absolute maximum ratings.

electrical characteristics at specified virtual junction temperature, $V_I = 11 V$, $I_O = 350 mA$, $T_J = 25^{\circ}C$ (unless otherwise noted)

				μ Α78Μ06C			UNIT
PARAMETER		ST CONDITIONS	1	MIN	ΤΥΡ	MAX	
• • • • • • • • • • • • • • • • • • •				5.75	6	6.25	v
Output voltage‡	IO = 5 mA to 350 mA,	VI = 8 V to 21 V,	Tj = 0°C to 125°C	5.7		6.3	ľ
	La 000 m t		V ₁ = 8 V to 25 V		5	100	m۷
Input voltage regulation	I _O = 200 mA		V ₁ = 9 V to 25 V		1.5	50	10.0
Ripple rejection	V _I = 9 V to 19 V,	f = 120 Hz	I _O = 100 mA, T _J = 0°C to 125°C	59			dB
			i _O = 300 mA	59	80		
	IO = 5 mA to 500 mA				20	120	۳V
Output voltage regulation	IO = 5 mA to 200 mA				10	60	mv
Temperature coefficient of output voltage	l _O = 5 mA,	Tj = 0°C to 125°	°C		-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				45		μV
Dropout voltage					2		V
Bias current					4.5	6	mA
Dia anna tabana	V _I = 9 V to 25 V,	I _O = 200 mA,	T _J = 0°C to 125°C			0.8	
Bias current change	IO = 5 mA to 350 mA,	T _J = 0°C to 125°	<u>v</u>			0.5	mA
Short-circuit output current	Vi = 35 V				270		mA
Peak output current					0.7		A

[†] All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.



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electrical characteristics at specified virtual junction temperature, V_I = 14 V, I_O = 350 mA, T_J = 25°C (unless otherwise noted)

DADAMETED	TEST CONDITIONS [†]			μ	1 18.417		
PARAMETER	15	STCONDITION	51	MIN	TYP	MAX	UNIT
				7.7	· 8	8.3	
Output voltage ‡	$V_{j} = 10.5 V \text{ to } 23 V,$ T _J = 0°C to 125°C	I _O = 5 mA to 35	50 mA,	7.6		8.4	v
	1- 000 mA		VI = 10.5 V to 25 V		6	100	
Input voltage regulation	1 _O = 200 mA		VI = 11 V to 25 V		2	50	mV
Ripple rejection	$V_{I} = 11.5 \text{ V to } 21.5 \text{ V}, f = 120 \text{ Hz} \qquad \begin{bmatrix} I_{O} = 100 \text{ mA}, \\ T_{J} = 0^{\circ}\text{C to } 125^{\circ}\text{C} \\ \hline I_{O} = 300 \text{ mA} \end{bmatrix}$	I _O = 100 mA, T _J = 0°C to 125°C	56			dB	
		lo = 300 mA	56	80			
	IO = 5 mA to 500 mA		· · · · · · · · · · · · · · · · · · ·		25	160	
Output voltage regulation	IO = 5 mA to 200 mA				10	60	mV
Temperature coefficient of output voltage	l _O = 5 mA,	T _J = 0°C to 12!	5°C		-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				52		μV
Dropout voltage					2		v
Bias current					4.6	6	mA
Dies surrent shortes	V _I = 10.5 V to 25 V,	IO = 200 mA, TJ = 0°C to 125°C	T _J = 0°C to 125°C			0.8	
Bias current change	IO = 5 mA to 350 mA,	Tj = 0°C to 12	5°C			0.5	mA
Short-circuit output current	VI = 35 V				250		mA
Peak output current					0.7		A

[†] All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

[‡] This specification applies only for dc power dissipation permitted by absolute maximum ratings.

electrical characteristics at specified virtual junction temperature, V_I = 16 V, I_O = 350 mA, T_J = 25°C (unless otherwise noted)

	TEST CONDITIONS			μ Α78M09C			
PARAMETER				MIN	TYP	MAX	UNIT
				8.6	9	9.4	
Output voltage‡	V _I = 11.5 V to 24 V, T _J = 0°C to 125°C	$I_{O} = 5 \text{ mA to } 3$	50 mA,	8.5		9.5	v
	1. 000 - 1		V ₁ = 11.5 V to 26 V		6	100	
Input voltage regulation	I _O = 200 mA		V _I = 12 V to 26 V		2	50	mV
Ripple rejection	V ₁ = 13 V to 23 V,	f = 120 Hz	I _O = 100 mA, T _J = 0°C to 125°C	c 56			dB
			lo = 300 mA		80		
	IO = 5 mA to 500 mA				25	180	
Output voltage regulation	IO = 5 mA to 200 mA				10	90	mV
Temperature coefficient of output voltage	lo ≈ 5 mA,	T _J = 0°C to 12	5°C	Γ	-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				58		μV
Dropout voltage					2		V
Bias current					4.6	6	mA
Dia a successful al an an	V _I = 11.5 V to 26 V,	IO = 200 mA,	Tj = 0°C to 125°C			0.8	
Bias current change	IO = 5 mA to 350 mA,	Tj = 0°C to 12	5°C			0.5	mA
Short-circuit output current	Vi = 35 V				250		mA
Peak output current	1			t -	0.7		A

[†] All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.



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electrical characteristics at specified virtual junction temperature, $V_I = 17 V$, $I_O = 350 mA$, $T_J = 25^{\circ}C$ (unless otherwise noted)

DADANETED	TEST CONDITIONST			μ Α78Μ10C			
PARAMETER				MIN	TYP	MAX	UNIT
				9.6	10	10.4	
Output voltage‡	V _I = 12.5 V to 25 V, T _J = 0°C to 125°C	l _O = 5 mA to 3	150 mA,	9.5		10.5	V
less traites	1		V ₁ = 12.5 V to 28 V		7	100	
Input voltage regulation	IO = 200 mA		Vi = 14 V to 28 V	2 50	2	2 50	mV
Ripple rejection	V _I = 15 V to 25 V, f = 120 Hz	f = 120 Hz	I _O = 100 mA, T _J = 0°C to 125°C	59	I		dB
			l _O = 300 mA	55	80		1
	IO = 5 mA to 500 mA				25	200	
Output voltage regulation	4O = 5 mA to 200 mA				10	100	m∨
Temperature coefficient of output voltage	lo = 5 mA,	T _J = 0°C to 12	5°C		-1		mV/°Ō
Output noise voltage	f = 10 Hz to 100 kHz				64		μV
Dropout voltage					2		V
Bias current					4.7	6	mA
Rice surrent shares	V _I = 12.5 V to 28 V,	IO = 200 mA,	T _J = 0°C to 125°C			0.8	
Bias current change	IO = 5 mA to 350 mA	, T _J = 0°C to 12	25°C			0.5	mA
Short-circuit output current	V _I = 35 V				245		mA
Peak output current					0.7		A

[†] All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

[‡] This specification applies only for dc power dissipation permitted by absolute maximum ratings.

electrical characteristics at specified virtual junction temperature, $V_I = 9 V$, $I_O = 350 mA$, $T_J = 25^{\circ}C$ (unless otherwise noted)

	TEST CONDITIONS			μ Α78Μ12C			
PARAMETER				MIN	TYP	MAX	UNIT
				11.5	12	12.5	
Output voltage ‡	VI = 14.5 V to 27 V, TJ = 0°C to 125°C	l _O = 5 mA to 35	50 mA,	11.4		12.6	V
	1- 000 1		V _I = 14.5 V to 30 V		8	100	mν
Input voltage regulation	I _O = 200 mA		V _I = 16 V to 30 V		2	50	mv.
Ripple rejection	·	f = 120 Hz	I _O = 100 mA, T _J = 0°C to 125°C	55			dB
		I _O = 300 mA	55	80		1	
	IO = 5 mA to 500 mA				25	240	
Output voltage regulation	10 = 5 mA to 200 mA				10	120	mV
Temperature coefficient of output voltage	l _O = 5 mA				-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				75		μV
Dropout voltage					2		v
Bias current					4.8	6	mA
Dia succession in the second sec	Vj = 14.5 V to 30 V,	lo = 200 mA,	T _J = 0°C to 125°C			0.8	
Bias current change	IO = 5 mA to 350 mA,	T _J = 0°C to 125	5°C			0.5	mA
Short-circuit output current	Vj = 35 V				240		mA
Peak output current					0.7		A

[†] All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.



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electrical characteristics at specified virtual junction temperature, V_{I} = 23 V, I_{O} = 350 mA, T_{J} = 25°C (unless otherwise noted)

				μ Α78Μ15C			
PARAMETER	TE	ST CONDITION	51	MIN	TYP	MAX	UNIT
				14.4	15	15.6	
Output voltage‡	V _I = 17.5 V to 30 V, T _J = 0°C to 125°C	IO = 5 mA to 35	iộ mA,	14.25		15.75	v
	1. 000 - A		VI = 17.5 V to 30 V		10	100	mV
Input voltage regulation	1 _O = 200 mA		VI = 20 V to 30 V		3	50	mv
Ripple rejection	VI = 18.5 V to 28.5 V, f = 120 Hz	f = 120 Hz	l _O = 100 mA, T _J = 0°C to 125°C	54			dB
		lo = 300 mA	54	70			
A	IO = 5 mA to 500 mA		<u> </u>	25		300	۳V
Output voltage regulation	IO = 5 mA to 200 mA				10	150	mv
Temperature coefficient of output voltage	io = 5 mA,	Tj = 0°C to 125	5°C		-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				90		μV
Dropout voltage					2		v
Bias current					4.8	6	mA
Ring assument above	Vj = 17.5 V to 30 V,	l <mark>o</mark> ≖ 200 mA,	Tj = 0°C to 125°C			0.8	mA
Bias current change	I _O = 5 mA to 350 mA,	Tj = 0°C to 125	5°C			0.5	IIIA
Short-circuit output current	V ₁ = 35 V				240		mA
Peak output current					0.7		A

1 All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T₁ as close to T_A as possible. Thermal effects must be taken into account separately.

[‡] This specification applies only for dc power dissipation permitted by absolute maximum ratings.

electrical characteristics at specified virtual junction temperature, $V_I = 29$ V, $I_O = 350$ mA, $T_J = 25^{\circ}C$ (unless otherwise noted)

			-+	μ Α78Μ20C			UNIT
PARAMETER	TEST CONDITIONS [†]			MIN	TYP	MAX	
				19.2	20	20.8	
Output voltage ‡	$V_{I} = 23 V \text{ to } 35 V,$ $T_{J} = 0^{\circ}C \text{ to } 125^{\circ}C$			19		21	v
	1- 000 m t		V _I = 23 V to 35 V		10	100	mV
Input voltage regulation	l _O = 200 mA		VI = 24 V to 35 V		5	50	
Ripple rejection	$V_1 = 24 V \text{ to } 34 V,$	f = 120 Hz	I _O = 100 mA, T _J = 0°C to 125°C	53			dB
			1 _O = 300 mA	53	70		1
	IO = 5 mA to 500 mA				30	400	mV
Output voltage regulation	IO = 5 mA to 200 mA	4			10	200	mv
Temperature coefficient of output voltage	l _O = 5 mA,	Tj = 0°C to 12	5°C		-1.1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				110	_	μV
Dropout voltage					2		۷
Bias current					4.9	6	mA
D'a constata a constata	V _I = 23 V to 35 V,	l _O = 200 mA,	Tj = 0°C to 125°C			0.8	mA
Bias current change	$I_{O} = 5 \text{ mA to } 350 \text{ mA}, T_{J} = 0^{\circ}\text{C to } 125^{\circ}\text{C}$				0.5		
Short-circuit output current	V _I = 35 V				240		mA
Peak output current	Ť			1	0.7		A

1 All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.



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electrical characteristics at specified virtual junction temperature, $V_I = 33$ V, $I_O = 350$ mA, $T_J = 25^{\circ}C$ (unless otherwise noted)

			a+	μ	C	UNIT	
PARAMETER	TEST CONDITIONS [†]			MIN	ТҮР	MAX	
				23	24	25	
Output voltage [‡]	/j = 27 V to 38 V, I _O = 5 mA to 350 mA, /j = 0°C to 125°C			22.8		25.2	v
	10 200 mA		Vi = 27 V to 38 V		10	100	
Input voltage regulation	IO = 200 mA		V ₁ = 28 V to 38 V		5	50	mV
Ripple rejection	VI = 28 V to 38 V,	f = 120 Hz	I _O = 100 mA, T _J = 0°C to 125°C	50			dB
			IO = 300 mA	50	70		
• · · · • • • · ·	IO = 5 mA to 500 mA				30	480	
Output voltage regulation	IO = 5 mA to 200 mA				10	240	m∨
Temperature coefficient of output voltage	IO = 5 mA,	T _J = 0°C to 125	5°C		-1.2		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				170		μV
Dropout voltage					2		V
Bias current					5	6	mA
Dia a summer a bara a	V ₁ = 27 V to 38 V,	l _O = 200 mA,	T _J = 0°C to 125°C			0.8	
lias current change	$t_0 = 5 \text{ mA to } 350 \text{ mA}, T_J = 0^{\circ}\text{C to } 125^{\circ}\text{C}$		1		0.5	mA	
Short-circuit output current	V _I = 35 V				240		mA
Peak output current			-		0.7		A

[†] All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_L as close to T_A as possible. Thermal effects must be taken into account separately.



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electrical characteristics at specified virtual junction temperature, $V_I = 10 V$, $I_O = 350 mA$, $T_J = 25^{\circ}C$ (unless otherwise noted)

	TEST CONDITIONS [†]		μ./				
PARAMETER	1 1	EST CONDITION	SI	MIN	TYP	MAX	UNIT
Output voltage‡					5		v
· · · · · · · · · · · · · · · · · · ·		O = 200 mA			3		
Input voltage regulation	IO = 200 mA			1			mV
Ripple rejection	V _I = 8 V to 18 V,	IO = 300 mA,	f = 120 Hz		80		dB
	IO = 5 mA to 500 mA				20		
Output voltage regulation	I _O = 5 mA to 200 mA	O = 5 mA to 200 mA		10			mV
Temperature coefficient of output voltage	I _O = 5 mA				-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				40		μV
Dropout voltage				Τ	2	_	V
Bias current	1			1	4.5		mA
Short-circuit output current	Vi = 35 V	_			300		mA
Peak output current				1	0.7		A

[†] All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

[‡] This specification applies only for dc power dissipation permitted by absolute maximum ratings.

electrical characteristics at specified virtual junction temperature, $V_I = 11 V$, $I_O = 350 mA$, $T_J = 25^{\circ}C$ (unless otherwise noted)

24 24 14 27 22	TEST CONDITIONS		μ Α78M06Y				
PARAMETER		IEST CONDITIONS	1	MIN	TYP	MAX	UNIT
Output voltage‡				1	6		V
terrest and the second states			V ₁ = 8 V to 25 V	5			
Input voltage regulation	I _O = 200 mA		V _I = 9 V to 25 V		1.5		mV
Ripple rejection	V _I = 9 V to 19 V, I _O = 300 mA, f = 120 Hz			80			dB
	O = 5 mA to 500 mA			20			
Output voltage regulation	IO = 5 mA to 200 m/	IO = 5 mA to 200 mA			10		m∨
Temperature coefficient of output voltage	l _O = 5 mA				- 1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz	2			45		μV
Dropout voltage					2		V I
Bias current					4.5		mA
Short-circuit output current	V _I = 35 V				270		mA
Peak output current					0.7		A

[†] All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-lesting techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.



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electrical characteristics at specified virtual junction temperature, $V_I = 14 V$, $I_O = 350 mA$, $T_J = 25^{\circ}C$ (unless otherwise noted)

			μ			
PARAMETER	TEST CONDITION	SI	MIN	ТҮР	MAX	UNIT
Output voltage ‡				8		V
Input voltage regulation		V _I = 10.5 V to 25 V	6			mv
	l _O = 200 mA	V _I = 11 V to 25 V		2		
Ripple rejection	VI = 11.5 V to 21.5 V, IO = 300 mA,	f = 120 Hz		80		dB
• · · · ·	O ≈ 5 mA to 500 mA		25			mv
Output voltage regulation	IO = 5 mA to 200 mA	IO = 5 mA to 200 mA		10		1
Temperature coefficient of output voltage	1 _O = 5 mA			1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz			52		μV
Dropout voltage				2		V
Bias current	•			4.6		mA
Short-circuit output current	VI = 35 V			250		mA
Peak output current				0.7		A

↑ All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

[‡]This specification applies only for dc power dissipation permitted by absolute maximum ratings.

electrical characteristics at specified virtual junction temperature, $V_I = 16 V_{,IO} = 350 mA$, $T_J = 25^{\circ}C$ (unless otherwise noted)

	TEST CONDITIONS		μΑ78Μ09Υ			UNIT	
PARAMETER	TI TI	EST CONDITION	51	MIN	TYP	MAX	
Output voltage ‡					9		V
Input voltage regulation	l _O = 200 mA		$V_{I} = 11.5 V \text{ to } 26 V$ $V_{I} = 12 V \text{ to } 26 V$		6 2		m∨
Ripple rejection	VI = 13 V to 23 V,	I _O = 300 mA,	f = 120 Hz		80		dB
	I _O = 5 mA to 500 mA		25			mv	
Output voltage regulation	IO = 5 mA to 200 mA	IO = 5 mA to 200 mA			10		
Temperature coefficient of output voltage	l⊖ = 5 mA,	Tj = 0°C to 125	5°C		-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				58		μV
Dropout voltage					2		V
Bias current					4.6		mA
Short-circuit output current	V ₁ = 35 V				250		mA
Peak output current					0.7		A

[†] All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_L as close to T_A as possible. Thermal effects must be taken into account separately.



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electrical characteristics at specified virtual junction temperature, $V_I = 17$ V, $I_O = 350$ mA, $T_J = 25^{\circ}C$ (unless otherwise noted)

	TEST CONDITIONS [†]		μΑ78Μ10Υ					
PARAMETER	15:	ST CONDITION:	51	MIN	TYP	MAX	UNIT	
Output voltage ‡					10		V	
Input voltage regulation	1- 000 0	O ≈ 200 mA		7				
	IO = 200 mA			2			m∨	
Ripple rejection	Vj = 15 V to 25 V,	1 _O = 300 mA,	f = 120 Hz		80		dB	
	IO = 5 mA to 500 mA		25					
Output voltage regulation	IO = 5 mA to 200 mA	Io = 5 mA to 200 mA			10		 ™V	
Temperature coefficient of output voltage	IO = 5 mA				-1		mV/ºC	
Output noise voltage	f = 10 Hz to 100 kHz				64		μV	
Dropout voltage			-		2		V	
Bias current	1				4.7		mA	
Short-circuit output current	VI = 35 V			İ —	245		mA	
Peak output current					0.7		A	

[†] All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

[‡] This specification applies only for dc power dissipation permitted by absolute maximum ratings.

electrical characteristics at specified virtual junction temperature, $V_I = 9 V$, $I_O = 350 mA$, $T_J = 25^{\circ}C$ (unless otherwise noted)

	TEST CONDITIONS		μ				
PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
Output voltage‡					12		V
Input voltage regulation	1 - 000 m t	- 200 mA			8		
	i _O = 200 mA		Vj = 16 V to 30 V		2		m∨
Ripple rejection	V ₁ = 15 V to 25 V,	Io = 300 mA,	f = 120 Hz		80		dB
Outer traffic a constantion	O = 5 mA to 500 mA			25			
Output voltage regulation	IO = 5 mA to 200 mA) = 5 mA to 200 mA		10			mV
Temperature coefficient of output voltage	IO = 5 mA				-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				75		μV
Dropout voltage					2		V
Bias current					4.8		mA
Short-circult output current	Vj = 35 V				240		mA
Peak output current	1				0.7		A

T All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.



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electrical characteristics at specified virtual junction temperature, V_I = 23 V, I_O = 350 mA, T_J = 25°C (unless otherwise noted)

DADAMETED	TEST CONDITIONS		μ Α78Μ15C			
PARAMETER	TEST CONDITION	IS I	MIN	TYP	MAX	UNIT
Output voltage‡				15		V
Input voltage regulation		V ₁ = 17.5 V to 30 V	10			
	l _O = 200 mA	VI = 20 V to 30 V		3		m∨
Ripple rejection	VI = 18.5 V to 28.5 V, IO = 300 mA,	f = 120 Hz		70		dB
	I _O = 5 mA to 500 mA I _O = 5 mA to 200 mA		25			
Output voltage regulation				10		m∨
Temperature coefficient of output voltage	1 ₀ = 5 mA			-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz			90		μV
Dropout voltage				2		V
Bias current				4.8		mA
Short-circuit output current	V _I = 35 V			240		mA
Peak output current				0.7		A

t All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

[‡] This specification applies only for dc power dissipation permitted by absolute maximum ratings.

electrical characteristics at specified virtual junction temperature, $V_I = 29 V$, $I_O = 350 mA$, $T_J = 25^{\circ}C$ (unless otherwise noted)

DADAMETED	TEST CONDITIONST		μ Α78Μ20C			1.0017	
PARAMETER	TESI	CONDITIONS	j I	MIN	TYP	MAX	UNIT
Output voltage‡					20		V
Input voltage regulation	la - 200 mt		V _I = 23 V to 35 V	10		mV	
	IO = 200 mA		V _I = 24 V to 35 V				
Ripple rejection	V _I = 24 V to 34 V, f =	= 120 Hz,	lO = 300 mA		70		dB
Output unknow regulation	I _O = 5 mA to 500 mA		30			mV	
Output voltage regulation	IO = 5 mA to 200 mA	O = 5 mA to 200 mA			10		
Temperature coefficient of output voltage	1 _O = 5 mA				-1.1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				110		μV
Dropout voltage					2		V
Bias current					4.9		mA
Short-circuit output current	Vj = 35 V				240		mA
Peak output current					0.7		A

[†] All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.



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electrical characteristics at specified virtual junction temperature, V_I = 33 V, I_O = 350 mA, T_J = 25°C (unless otherwise noted)

			μΑ78Μ24Υ		Ŷ	
PARAMETER	TEST CONDITIO	JNS I	MIN	TYP	MAX	UNIT
Output voltage‡				24		v
		Vj = 27 V to 38 V	10			
Input voltage regulation	t _O	Vi = 28 V to 38 V	5			m∨
Ripple rejection	V _I = 28 V to 38 V, I _O = 300 mA	, f = 120 Hz		70		dB
	I _O = 5 mA to 500 mA		30			
Output voltage regulation	IO = 5 mA to 200 mA	IQ = 5 mA to 200 mA		10		mV
Temperature coefficient of output voltage	l _O = 5 mA		1	-1.2		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz			170		μV
Dropout voltage				2		V
Bias current				5		mA
Short-circuit output current	VI = 35 V			240		mA
Peak output current			<u> </u>	0.7		A

t All characteristics are measured with a 0.33-µF capacitor across the input and a 0.1-µF capacitor across the output. Pulse-testing techniques

maintain TJ as close to TA as possible. Thermal effects must be taken into account separately.

